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### BDW93/A/B/C

### Hammer Drivers, Audio Amplifiers Applications

- Power Darlington TR
- Complement to BDW94, BDW94A, BDW94B and BDW94C respectively



1.Base 2.Collector 3.Emitter

### **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       |            |       |
|                  | : BDW93                                      | 45         | V     |
|                  | : BDW93A                                     | 60         | V     |
|                  | : BDW93B                                     | 80         | V     |
|                  | : BDW93C                                     | 100        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    |            |       |
|                  | : BDW93                                      | 45         | V     |
|                  | : BDW93A                                     | 60         | V     |
|                  | : BDW93B                                     | 80         | V     |
|                  | : BDW93C                                     | 100        | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 12         | А     |
| I <sub>CP</sub>  | *Collector Current (Pulse)                   | 15         | А     |
| I <sub>B</sub>   | Base Current                                 | 0.2        | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 80         | W     |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 65 ~ 150 | °C    |

### Thermal Characteristics $T_C=25^{\circ}C$ unless otherwise noted

| Symbol          | Parameter          |                  | Value | Units |
|-----------------|--------------------|------------------|-------|-------|
| $R_{\theta jc}$ | Thermal Resistance | Junction to Case | 1.5   | °C/W  |

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|                   | <b>^!</b>   |
|-------------------|---|
| <b>FIACTRICAL</b> | Characteristics T <sub>C</sub> =25°C unless otherwise noted |
| Liccuitai         | Offaracter istres in =25 c unless offerwise noted           |

| Symbol                  | Parameter   | Test Condition   | Min.                  | Тур.       | Max.                     | Units                |
|-------------------------|---|--|-----------------------|------------|--------------------------|----------------------|
| BV <sub>CEO</sub> (sus) | * Collector-Emitter Sustaining Voltage<br>: BDW93<br>: BDW93A<br>: BDW93B<br>: BDW93C | I <sub>C</sub> = 100mA, I <sub>B</sub> = 0   | 45<br>60<br>80<br>100 |            |                          | V<br>V<br>V          |
| І <sub>СВО</sub>        | Collector Cut-off Current : BDW93 : BDW93A : BDW93B : BDW93C                          | $V_{CB} = 45V, I_{E} = 0$ $V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$ $V_{CB} = 100V, I_{E} = 0$ |                       |            | 100<br>100<br>100<br>100 | μΑ<br>μΑ<br>μΑ<br>μΑ |
| I <sub>CEO</sub>        | Collector Cut-off Current : BDW93 : BDW93A : BDW93B : BDW93C                          | $V_{CE} = 45V, I_B = 0$ $V_{CE} = 60V, I_B = 0$ $V_{CE} = 80V, I_B = 0$ $V_{CE} = 100V, I_B = 0$         |                       |            | 1<br>1<br>1              | mA<br>mA<br>mA       |
| I <sub>EBO</sub>        | Emitter Cut-off Current   | $V_{EB} = 5V, I_{C} = 0$   |                       |            | 2                        | mA                   |
| h <sub>FE</sub>         | * DC Current Gain   | $V_{CE} = 3V, I_{C} = 3A$ $V_{CE} = 3V, I_{C} = 5A$ $V_{CE} = 3V, I_{C} = 10A$                           | 1000<br>750<br>100    |            | 20000                    |                      |
| V <sub>CE</sub> (sat)   | * Collector-Emitter Saturation Voltage  | $I_C = 5A$ , $I_B = 20mA$<br>$I_C = 10A$ , $I_B = 100mA$   |                       |            | 2 3                      | V<br>V               |
| V <sub>BE</sub> (sat)   | * Base-Emitter Saturation Voltage   | $I_C = 5A$ , $I_B = 20mA$<br>$I_C = 10A$ , $I_B = 100mA$   |                       |            | 2.5<br>4                 | V<br>V               |
| V <sub>F</sub>          | * Parallel Diode Forward Voltage  | I <sub>F</sub> = 5A<br>I <sub>F</sub> = 10A  |                       | 1.3<br>1.8 | 2<br>4                   | V<br>V               |

<sup>\*</sup> Pulse Test: PW=300μs, duty Cycle =1.5% Pulsed

# **Typical characteristics**

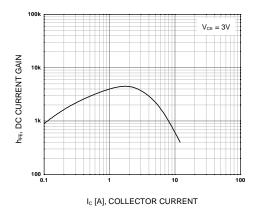


Figure 1. DC Current Gain

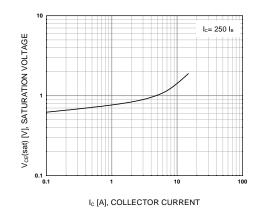


Figure 2. Collector-Emitter Saturation Voltage

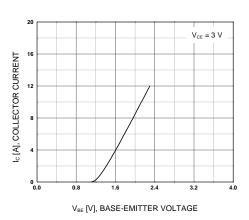


Figure 3. Base-Emitter On Voltage

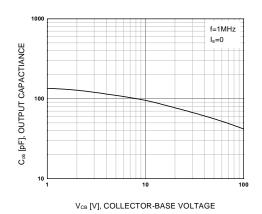


Figure 4. Collector Output Capacitance

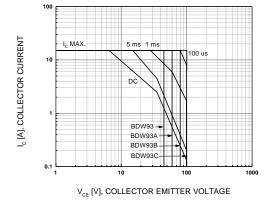


Figure 5. Safe Operating Area

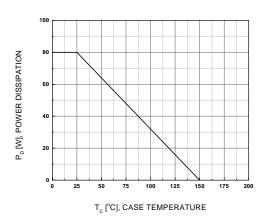
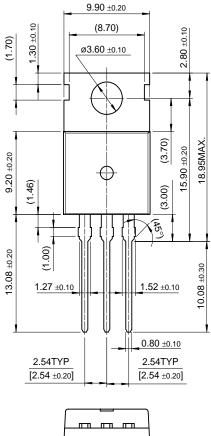


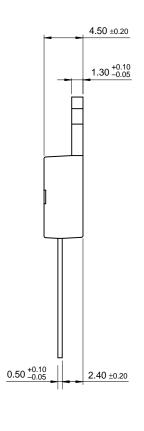
Figure 6. Power Derating

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# **Package Demensions**

## TO-220





10.00 ±0.20

Dimensions in Millimeters

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